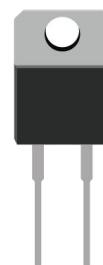


# 8A, 650V SIC Schottky Rectifier

## FEATURES

- 650V schottky rectifier
- Ceramic package provides 2.5KV isolation
- Zero reverse recovery current
- Zero forward recovery voltage
- Switching characteristics independent on temperature
- Positive temperature coefficient of forward voltage
- High temperature soldering guaranteed: 270°C/10 seconds
- RoHS compliant, halogen free

**TO-220AC**



**RoHS  
COMPLIANT**

**HALOGEN  
FREE**

## MECHANICAL DATA

- Case: TO-220AC
- Case material: molding compound meets UL 94V-0 flammability rating
- Polarity: as marked on case



## TYPICAL APPLICATION

General purpose use in HAVC,SMPS, AC/DC converters,free wheeling diodes in inverter stages.

## MAXIMUM RATINGS

$T_J=25^\circ\text{C}$  unless otherwise noted

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	650	V
Average Forward Rectified Current	$I_F$	8	A
Repetitive Peak Forward Surge Current ( $t_p=10\text{ms}, T_c=25^\circ\text{C}$ )	$I_{FRM}$	65	A
Peak Forward Surge Current ( $t_p=10\text{ms}, T_c=25^\circ\text{C}$ )	$I_{FSM}$	80	A
Non-Repetitive peak forward surge current ( $t_p = 10 \mu\text{s}; T_c = 25^\circ\text{C}$ , pulse)	$I_{Fmax}$	500	A
Power Dissipation $T_c=25^\circ\text{C}$ $T_c=110^\circ\text{C}$	$P_{tot}$	117 51	W
Operating Junction Temperature Range	$T_J$	-55 to +175	°C
Storage Temperature Range	$T_{STG}$	-55 to +175	°C

## ELECTRICAL CHARACTERISTICS

$T_J=25^\circ\text{C}$  unless otherwise noted

Parameter	Test Conditions	Symbol	Value		Unit
			Typ.	Max.	
Forward Voltage@ $I_F=8\text{A}$	$T_J=25^\circ\text{C}$	$V_F$	1.35	1.65	V
	$T_J=175^\circ\text{C}$		1.85	2.35	
Reverse Current @ $V_{RRM}$	$T_J=25^\circ\text{C}$	$I_R$	5	20	$\mu\text{A}$
	$T_J=175^\circ\text{C}$		30	80	
Total Capacitance	$V_R=0\text{V}, f=1\text{MHz}$	C	470	-	$\text{pF}$
	$V_R=200\text{V}, f=1\text{MHz}$		40	-	
	$V_R=400\text{V}, f=1\text{MHz}$		32	-	
Total Capacitance Charge	$V_R=400\text{V}$	$Q_C$	30	-	nC
Capacitance Stored Energy	$V_R=400\text{V}$	$E_C$	6	-	$\mu\text{J}$
Thermal Resistance	Junction to case	$R_{\theta JC}$	2.1		°C/W

# **8A, 650V SiC Schottky Rectifier**

## RATINGS AND CHARACTERISTIC CURVES

FIG.1: Forward Characteristics

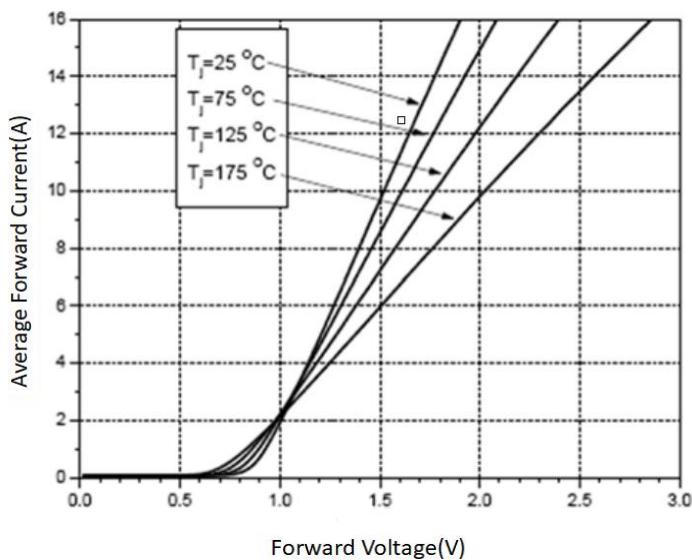


FIG.3: Capacitance Charge vs. Reverse Voltage

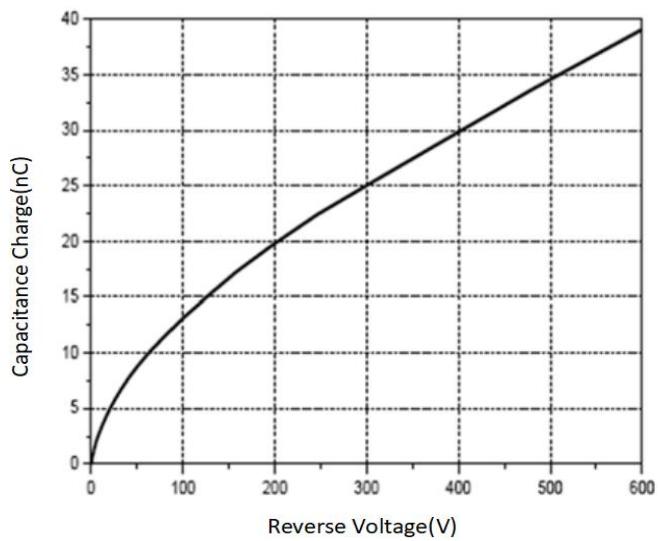


FIG.5: Power Derating

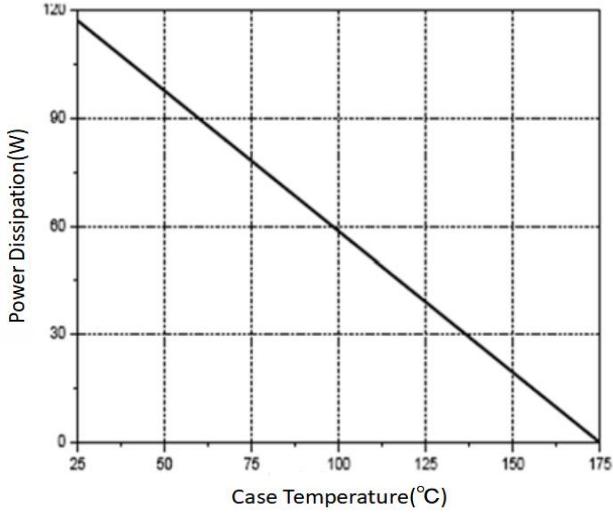


FIG.2: Reverse Characteristics

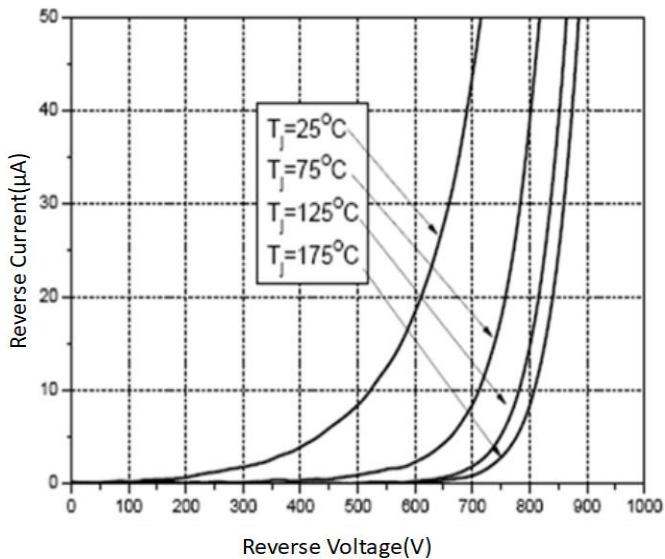


FIG.4: Capacitance Stored Energy

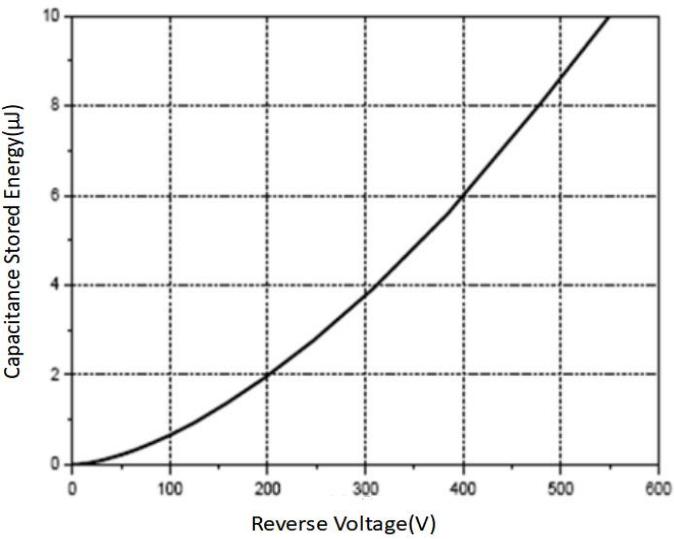
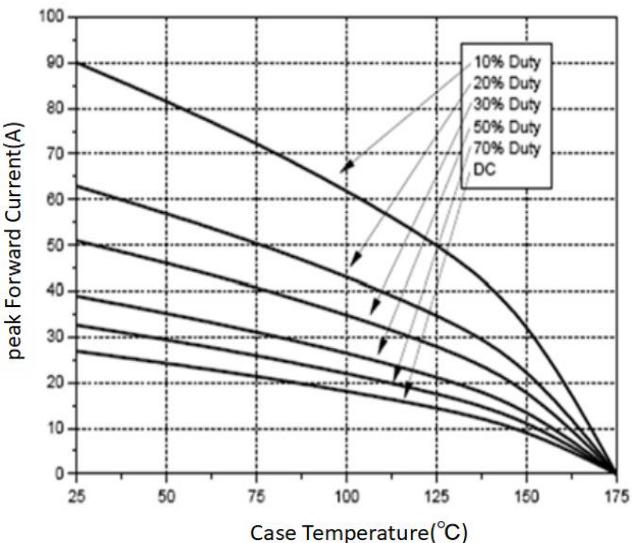
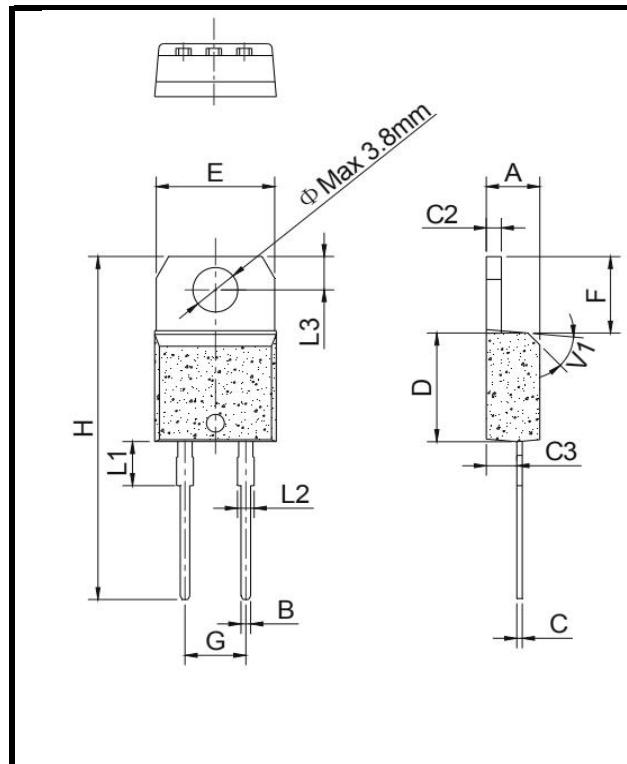


FIG.6: Current Derating



# 8A, 650V SiC Schottky Rectifier

## PACKAGE OUTLINE DIMENSIONS



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		5.08			0.2	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

## PACKING INFORMATION

Package	Tube(PCS)	Inner Box(PCS)	Carton(PCS)
TO-220AC	50	1,000	5,000